



Features

- Low ON resistance.
- Very high-speed switching.
- Low-voltage drive.
- Its height onboard is 9.5mm.
- Meets radial taping.

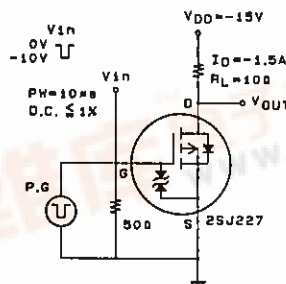
Absolute Maximum Ratings at Ta = 25°C

			unit
Drain to Source Voltage	V _{DSS}	-30	V
Gate to Source Voltage	V _{GSS}	±15	V
Drain Current(DC)	I _D	-3	A
Drain Current(Pulse)	I _{DP}	PW ≤ 10μs, duty cycle ≤ 1%	-12 A
Allowable Power Dissipation	P _D	1.5	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

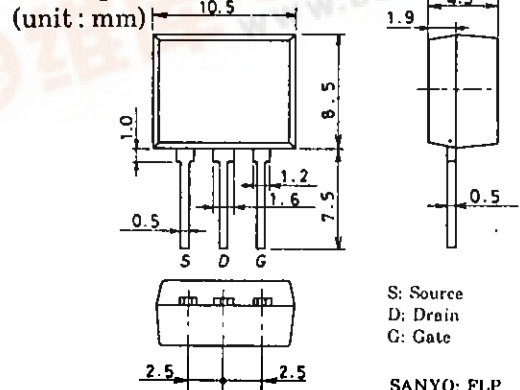
Electrical Characteristics at Ta = 25°C

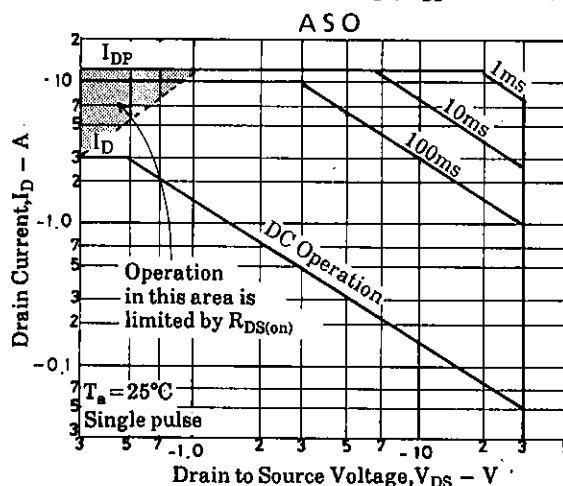
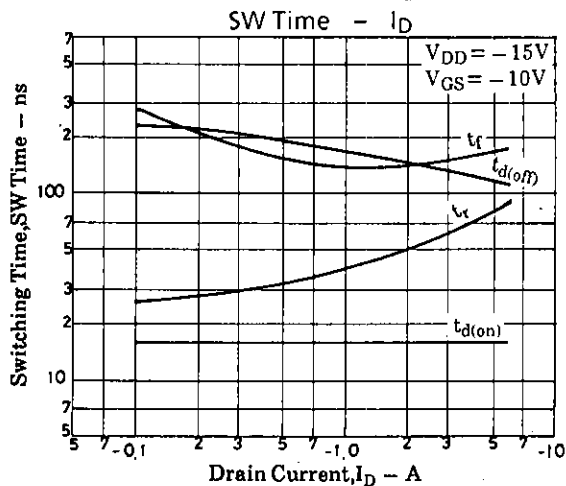
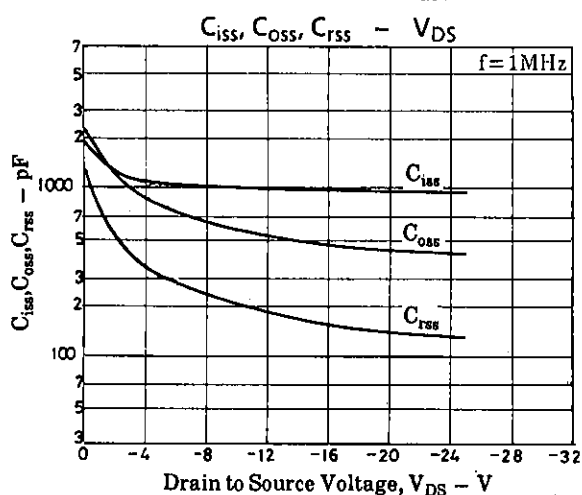
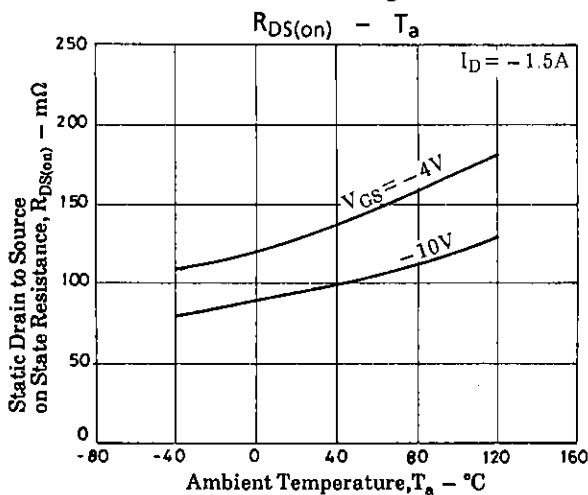
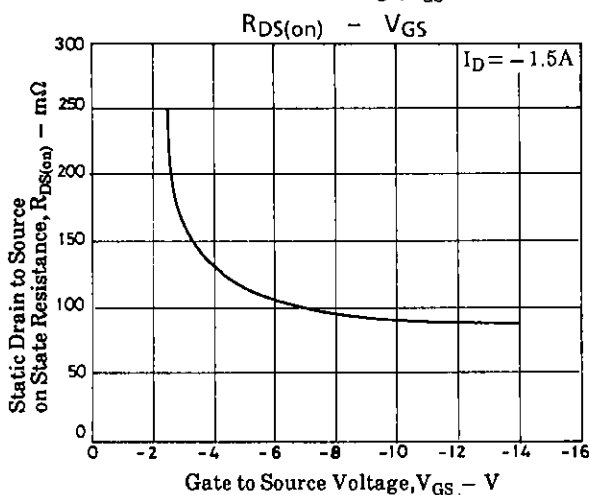
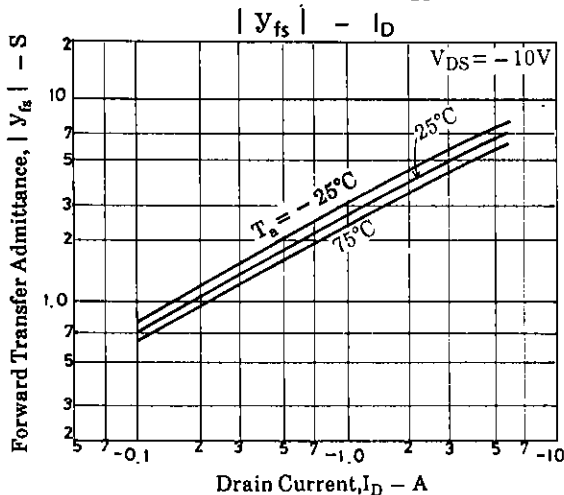
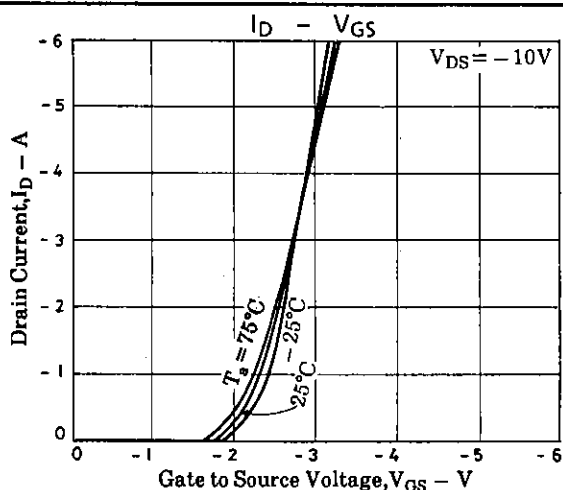
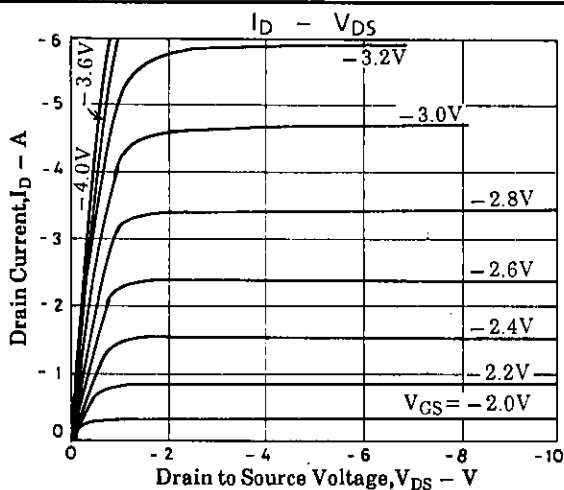
			min	typ	max	unit
D-S Breakdown Voltage	V(BR)DSS	I _D = -1mA, V _{GS} = 0	-30			V
G-S Breakdown Voltage	V(BR)GSS	I _G = ±100μA, V _{DS} = 0	±15			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -30V, V _{GS} = 0			-100	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±12V, V _{DS} = 0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} = -10V, I _D = -1mA	-1.0		-2.0	V
Forward Transfer Admittance	Y _{fs}	V _{DS} = -10V, I _D = -1.5A	2	3.5		S
Static Drain to Source on State Resistance	R _{DS(on)}	I _D = -1.5A, V _{GS} = -10V		95	130	mΩ
	R _{DS(on)}	I _D = -1.5A, V _{GS} = -4V		130	170	mΩ
Input Capacitance	C _{iss}	V _{DS} = -10V, f = 1MHz		1000		pF
Output Capacitance	C _{oss}	V _{DS} = -10V, f = 1MHz		600		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} = -10V, f = 1MHz		220		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		15		ns
Rise Time	t _r	∕		45		ns
Turn-OFF Delay Time	t _{d(off)}	∕		160		ns
Fall Time	t _f	∕		145		ns
Diode Forward Voltage	V _{SD}	I _S = -3A, V _{GS} = 0	-1.0	-1.5		V

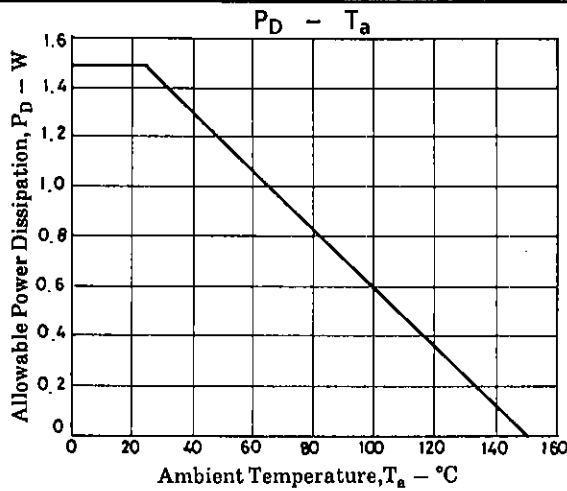
Switching Time Test Circuit



Package Dimensions 2085







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